

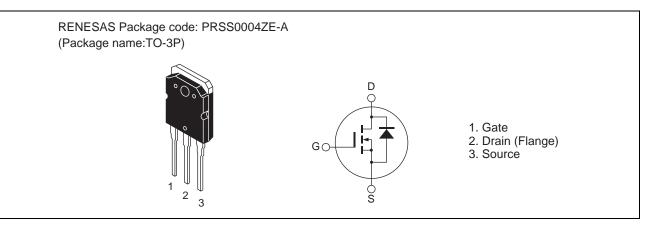
RJL5014DPK

Silicon N Channel MOS FET High Speed Power Switching R07DS0436EJ0200 (Previous: REJ03G1798-0100) Rev.2.00 Jun 14, 2011

Features

- Built-in fast recovery diode
- Low on-resistance
- $R_{DS(on)} = 0.32 \ \Omega \text{ typ.}$ (at $I_D = 9.5 \text{ A}$, $V_{GS} = 10 \text{ V}$, Ta = 25 °C)
- Low leakage current
- High speed switching

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$ Item Symbol Ratings Unit VDSS 500 V Drain to source voltage V ±30 Gate to source voltage V_{GSS} Drain current 19 А I_D Note1 Drain peak current I_{D (pulse)} 57 A Body-drain diode reverse drain current 19 А I_{DR} I_{DR (pulse)} Note3 Body-drain diode reverse drain peak current 57 А 4 А Avalanche current E_{AR}Note3 Avalanche energy 0.88 mJ Pch Note2 W Channel dissipation 150 °C/W Channel to case thermal impedance θch-c 0.833 Channel temperature Tch 150 °C -55 to +150 °C Storage temperature Tstg

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1 %

2. Value at Tc = 25°C

3. STch = 25°C, Tch \leq 150°C



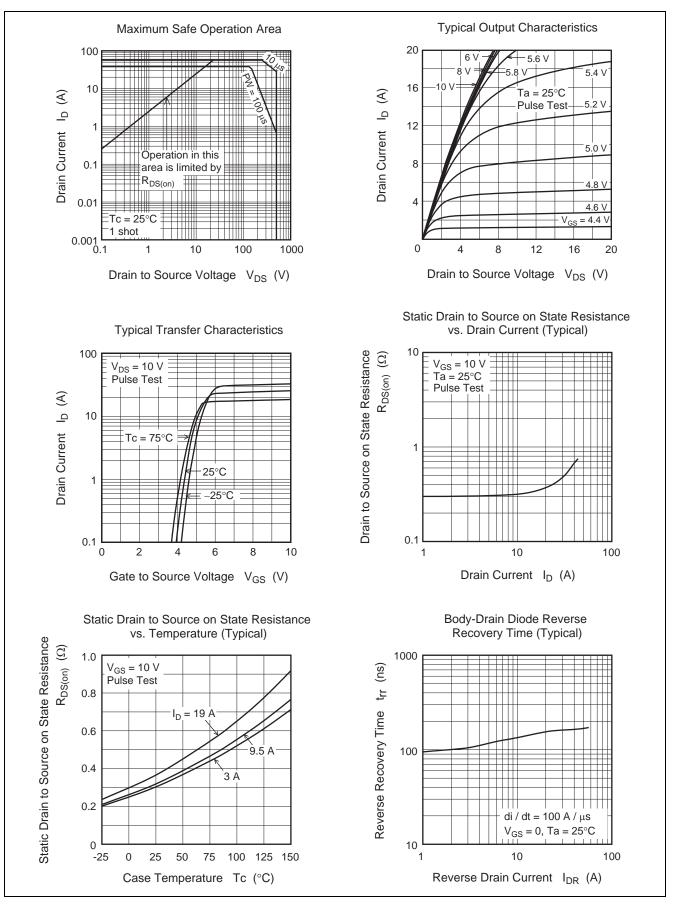
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	500	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}		—	10	μΑ	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS}=\pm 30~V,~V_{DS}=0$
Gate to source cutoff voltage	V _{GS(off)}	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	0.32	0.40	Ω	$I_D = 9.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance						
Input capacitance	Ciss	_	1700	_	pF	V _{DS} = 25 V
Output capacitance	Coss		190	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	23	—	pF	
Turn-on delay time	t _{d(on)}	_	32	—	ns	I _D = 9.5 A
Rise time	tr	_	27	—	ns	$V_{GS} = 10 V$ $R_L = 26.3 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	_	95	—	ns	
Fall time	t _f	_	20	—	ns	
Total gate charge	Qg	_	43	—	nC	V _{DD} = 400 V
Gate to source charge	Qgs	_	8.2	—	nC	V _{GS} = 10 V I _D = 19 A
Gate to drain charge	Qgd	_	21.8	—	nC	
Body-drain diode forward voltage	V _{DF}	_	1.00	1.65	V	$I_F = 19 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery time	t _{rr}		160	—	ns	$I_F = 19 \text{ A}, V_{GS} = 0$
						di _F /dt = 100 A/µs

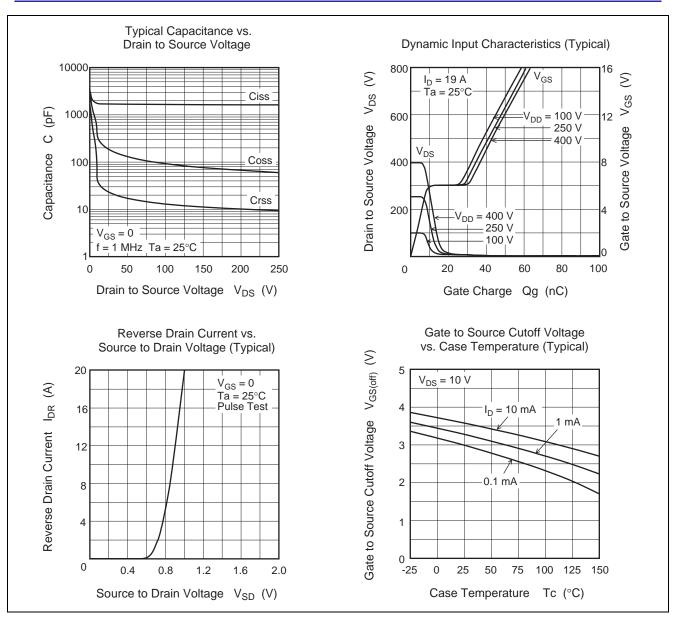
Notes: 4. Pulse test



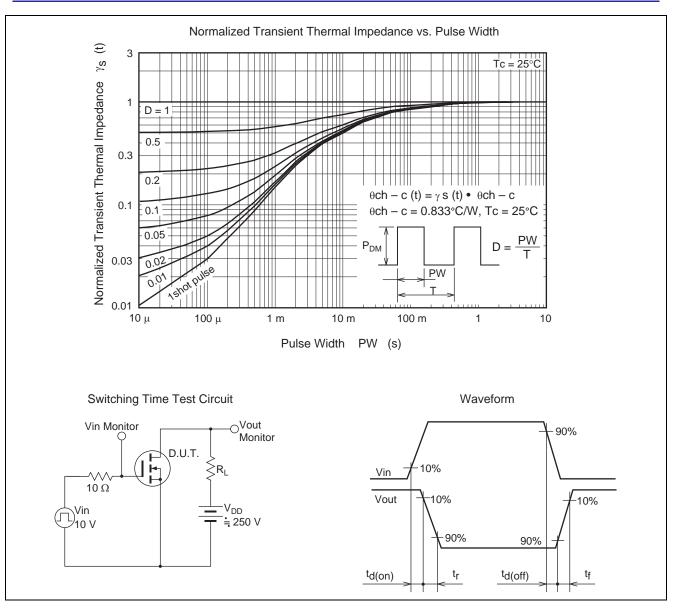
Main Characteristics













Package Dimensions

Package Name TO-3P	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	
TO-3P	SC-65	PRSS0004ZE-A	TO-3P / TO-3PV	5.0g	Unit: mm
	<u>1.6</u> <u>1.4 Ma</u>	$ \begin{array}{c} 15.6 \pm 0.3 \\ \phi 3.2 \pm 0.2 \\ \hline \hline \hline \hline \hline \hline \hline \hline \hline \hline \hline \hline \hline \hline $	$10^{\pm} 0.5$	4.8 ± 0.2 1.5 0.6 ± 0.2	
	5.45 ± 0		<u>.0</u> <u>.0</u> <u>.</u> <u>.5.45 ± 0.5</u>		

Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJL5014DPK-00-T0	360 pcs	Box (Tube)



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